# 74HC4052-Q100; 74HCT4052-Q100

**Dual 4-channel analog multiplexer/demultiplexer** 

Rev. 3 — 27 February 2020

**Product data sheet** 

### 1. General description

The 74HC4052-Q100; 74HCT4052-Q100 is a dual single-pole quad-throw analog switch (2x SP4T) suitable for use in analog or digital 4:1 multiplexer/demultiplexer applications. Each switch features four independent inputs/outputs (nY0, nY1, nY2 and nY3) and a common input/output (nZ). A digital enable input ( $\overline{E}$ ) and two digital select inputs (S0 and S1) are common to both switches. When  $\overline{E}$  is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- · Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide analog input voltage range from -5 V to +5 V
- Low ON resistance:
  - 80 Ω (typical) at V<sub>CC</sub> V<sub>EE</sub> = 4.5 V
  - 70  $\Omega$  (typical) at  $V_{CC}$   $V_{EE}$  = 6.0 V
  - 60 Ω (typical) at V<sub>CC</sub> V<sub>EE</sub> = 9.0 V
- Logic level translation: to enable 5 V logic to communicate with ±5 V analog signals
- Typical 'break before make' built-in
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2 000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
  - CDM AEC-Q100-011 revision B exceeds 1000 V
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

### 3. Applications

- · Analog multiplexing and demultiplexing
- · Digital multiplexing and demultiplexing
- Signal gating

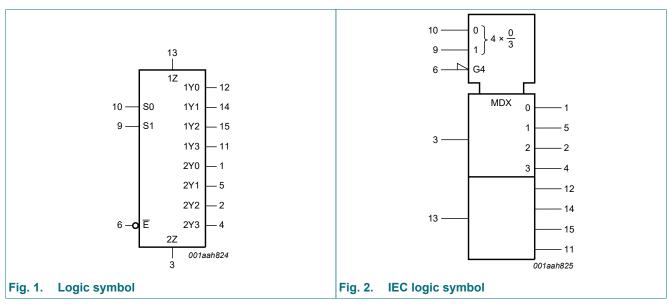


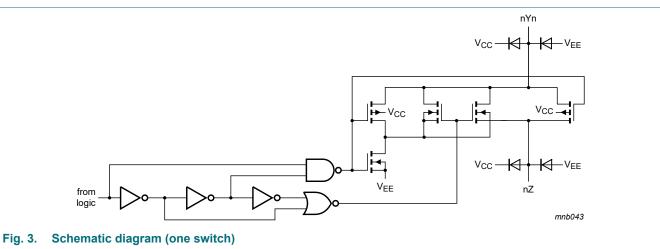
### 4. Ordering information

**Table 1. Ordering information** 

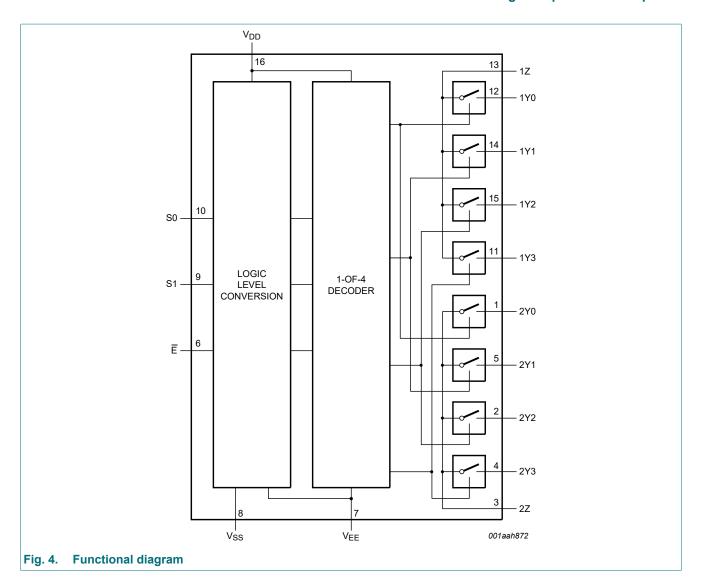
Type number	Package					
	Temperature range	Name	Description	Version		
74HC4052D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1		
74HCT4052D-Q100			body width 3.9 mm	SOT109-1		
74HC4052PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1		
74HCT4052PW-Q100			body width 4.4 mm			
74HC4052BQ-Q100	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal	SOT763-1		
74HCT4052BQ-Q100			enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm			

### 5. Functional diagram



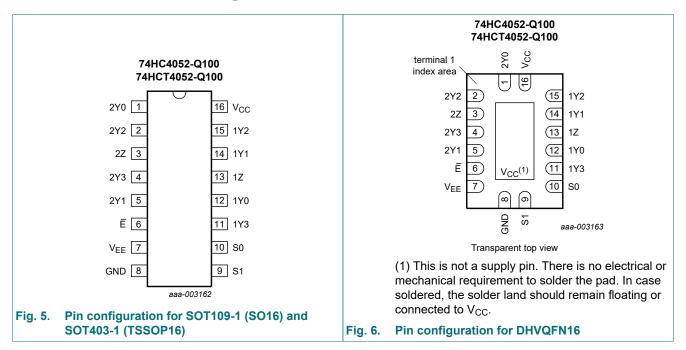


2 / 25



### 6. Pinning information

### 6.1. Pinning



#### 6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
2Y0, 2Y1, 2Y2, 2Y3	1, 5, 2, 4	independent input or output
1Z, 2Z	13, 3	common input or output
Ē	6	enable input (active LOW)
V <sub>EE</sub>	7	negative supply voltage
GND	8	ground (0 V)
S0, S1	10, 9	select logic input
1Y0, 1Y1, 1Y2, 1Y3	12, 14, 15, 11	independent input or output
V <sub>CC</sub>	16	positive supply voltage

4 / 25

### 7. Functional description

#### Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$ 

Input	nput			
Ē	S1	S0		
L	L	L	nY0 and nZ	
L	L	Н	nY1 and nZ	
L	Н	L	nY2 and nZ	
L	Н	Н	nY3 and nZ	
Н	X	X	none	

### 8. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Voltages are referenced to  $V_{EE}$  = GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage	[1]	-0.5	+11.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>SK</sub>	switch clamping current	$V_{SW}$ < -0.5 V or $V_{SW}$ > $V_{CC}$ + 0.5 V	-	±20	mA
I <sub>SW</sub>	switch current	-0.5 V < V <sub>SW</sub> < V <sub>CC</sub> + 0.5 V	-	±25	mA
I <sub>EE</sub>	supply current		-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-	-50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	[2]	-	500	mW
Р	power dissipation	per switch	-	100	mW

<sup>[1]</sup> To avoid drawing  $V_{CC}$  current out of pins nZ, when switch current flows in pins nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into pins nZ, no  $V_{CC}$  current will flow out of pins nYn. In this case there is no limit for the voltage drop across the switch, but the voltages at pins nYn and nZ may not exceed  $V_{CC}$  or  $V_{EE}$ .

[2] For SOT109-1 (SO16) package: P<sub>tot</sub> derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P<sub>tot</sub> derates linearly with 8.5 mW/K above 91 °C.

For SOT763-1 (DHVQFN16) package:  $P_{tot}$  derates linearly with 11.2 mW/K above 106 °C.

### 9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74F	IC4052-Q	100	74HCT4052-Q100		Unit	
			Min	Тур	Max	Min	Тур	Max	V V V V °C ns/V ns/V
V <sub>CC</sub>	supply voltage	see <u>Fig. 7</u> and <u>Fig. 8</u>							
		V <sub>CC</sub> - GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V <sub>CC</sub> - V <sub>EE</sub>	2.0	5.0	10.0	2.0	5.0	10.0	V
VI	input voltage		GND	-	V <sub>CC</sub>	GND	-	V <sub>CC</sub>	V
V <sub>SW</sub>	switch voltage		V <sub>EE</sub>	-	V <sub>CC</sub>	V <sub>EE</sub>	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
	fall rate	V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V
		V <sub>CC</sub> = 10.0 V	-	-	31	-	-	-	ns/V

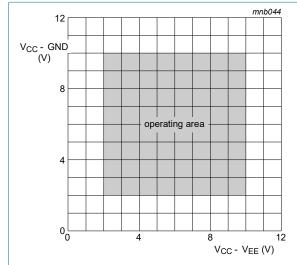


Fig. 7. Guaranteed operating area as a function of the supply voltages for 74HC4052-Q100

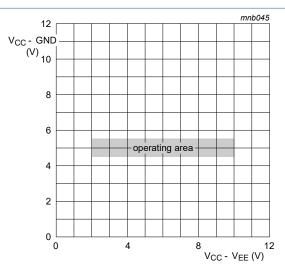


Fig. 8. Guaranteed operating area as a function of the supply voltages for 74HCT4052-Q100

### 10. Static characteristics

#### Table 6. R<sub>ON</sub> resistance per switch for 74HC4052-Q100 and 74HCT4052-Q100

 $V_I = V_{IH}$  or  $V_{IL}$ ; for test circuit see Fig. 9.

 $V_{is}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 $V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

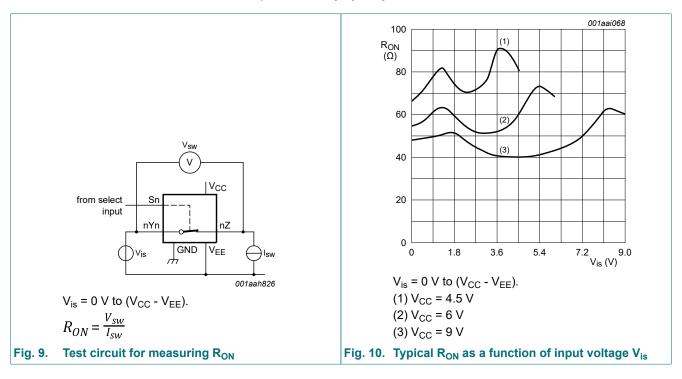
For 74HC4052-Q100:  $V_{\rm CC}$  - GND or  $V_{\rm CC}$  -  $V_{\rm EE}$  = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4052-Q100:  $V_{CC}$  - GND = 4.5 V and 5.5 V,  $V_{CC}$  -  $V_{EE}$  = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -4	0 °C to +85 °C						
R <sub>ON(peak)</sub>		V <sub>is</sub> = V <sub>CC</sub> to V <sub>EE</sub>					
	(peak)	V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[2]	-	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	100	225	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	90	200	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA		-	70	165	Ω
R <sub>ON(rail)</sub>	ON resistance (rail)	$V_{is} = V_{EE}$					
, ,		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[2]	-	150		Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	80	175	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	70	150	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA		-	60	130	Ω
		V <sub>is</sub> = V <sub>CC</sub>					
		$V_{CC}$ = 2.0 V; $V_{EE}$ = 0 V; $I_{SW}$ = 100 $\mu$ A	[2]	-	150	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	90	200	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	80	175	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA		-	65	150	Ω
ΔR <sub>ON</sub>	ON resistance	$V_{is} = V_{CC}$ to $V_{EE}$					
	mismatch between channels	V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	[2]	-	-	-	Ω
	Charmers	V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V		-	9	-	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V		-	8	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V		-	6	-	Ω
T <sub>amb</sub> = -4	0 °C to +125 °C						
R <sub>ON(peak)</sub>		V <sub>is</sub> = V <sub>CC</sub> to V <sub>EE</sub>					
*	(peak)	V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[2]	-	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	-	270	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	-	240	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA		-	-	195	Ω

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
R <sub>ON(rail)</sub>	ON resistance (rail)	$V_{is} = V_{EE}$					
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[2]	-	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	-	210	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	-	180	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA		-	-	160	Ω
		$V_{is} = V_{CC}$					
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 100 μA	[2]	-	-	-	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	-	240	Ω
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V; I <sub>SW</sub> = 1000 μA		-	-	210	Ω
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V; I <sub>SW</sub> = 1000 μA		-	-	180	Ω

- [1] All typical values are measured at  $T_{amb}$  = 25 °C.
- [2] When supply voltages (V<sub>CC</sub> V<sub>EE</sub>) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.



#### Table 7. Static characteristics for 74HC4052-Q100

Voltages are referenced to GND (ground = 0 V).

V<sub>is</sub> is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 $V_{os}$  is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C					_
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
		V <sub>CC</sub> = 9.0 V	6.3	4.7	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	8.0	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
		V <sub>CC</sub> = 9.0 V	-	4.3	2.7	V
l <sub>l</sub>	input leakage current	V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> or GND				
		V <sub>CC</sub> = 6.0 V	-	-	±1.0	μΑ
		V <sub>CC</sub> = 10.0 V	-	-	±2.0	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±2.0	μΑ
I <sub>S(ON)</sub>	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±2.0	μA
I <sub>CC</sub>	supply current	$V_{EE}$ = 0 V; $V_{I}$ = $V_{CC}$ or GND; $V_{is}$ = $V_{EE}$ or $V_{CC}$ ; $V_{os}$ = $V_{CC}$ or $V_{EE}$				
		V <sub>CC</sub> = 6.0 V	-	-	80.0	μA
		V <sub>CC</sub> = 10.0 V	-	-	160.0	μΑ
Cı	input capacitance		-	3.5	-	pF
C <sub>sw</sub>	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	12	-	pF
T <sub>amb</sub> = -	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
		V <sub>CC</sub> = 9.0 V	6.3	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	±2.0 µA  80.0 µA  160.0 µA  - pF  - pF  - V  - V	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
		V <sub>CC</sub> = 9.0 V	-	-	2.7	V

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I <sub>I</sub>	input leakage current	V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>CC</sub> or GND				
		V <sub>CC</sub> = 6.0 V	-	-	±1.0	μΑ
		V <sub>CC</sub> = 10.0 V	-	-	±2.0	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	$V_{CC}$ = 10.0 V; $V_{EE}$ = 0 V; $V_{I}$ = $V_{IH}$ or $V_{IL}$ ; $ V_{SW} $ = $V_{CC}$ - $V_{EE}$ ; see Fig. 11				
		per channel	-	-	±1.0	μΑ
		all channels	-	-	±2.0	μΑ
I <sub>S(ON)</sub>	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±2.0	μA
I <sub>CC</sub>	supply current	$V_{EE}$ = 0 V; $V_{I}$ = $V_{CC}$ or GND; $V_{is}$ = $V_{EE}$ or $V_{CC}$ ; $V_{os}$ = $V_{CC}$ or $V_{EE}$				
		V <sub>CC</sub> = 6.0 V	-	-	160.0	μΑ
		V <sub>CC</sub> = 10.0 V	-	-	320.0	μΑ

<sup>[1]</sup> All typical values are measured at  $T_{amb}$  = 25 °C.

#### Table 8. Static characteristics for 74HCT4052-Q100

Voltages are referenced to GND (ground = 0 V).

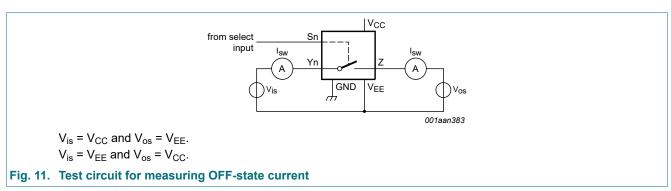
 $V_{is}$  is the input voltage at pins nYn or nZ, whichever is assigned as an input.

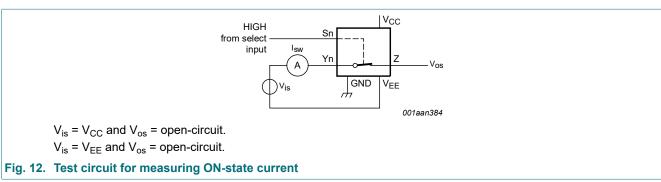
 $V_{os}$  is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -4	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
$V_{IL}$	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μA
		all channels	-	-	±2.0	μΑ
I <sub>S(ON)</sub>	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±2.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or $V_{CC}$ ; $V_{os} = V_{CC}$ or $V_{EE}$				
		V <sub>CC</sub> = 5.5 V; V <sub>EE</sub> = 0 V	-	-	80.0	μΑ
		V <sub>CC</sub> = 5.0 V; V <sub>EE</sub> = -5.0 V	-	-	160.0	μΑ
ΔI <sub>CC</sub>	additional supply current	per input; $V_I = V_{CC}$ - 2.1 V; other inputs at $V_{CC}$ or GND; $V_{CC}$ = 4.5 V to 5.5 V; $V_{EE}$ = 0 V	-	45	202.5	μΑ
Cı	input capacitance		-	3.5	-	pF
C <sub>sw</sub>	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	12	-	pF

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -4	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$ ; $V_{EE} = 0 \text{ V}$	-	-	±1.0	μΑ
I <sub>S(OFF)</sub>	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μA
		all channels	-	-	±2.0	μA
I <sub>S(ON)</sub>	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL};$ $ V_{SW}  = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±2.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or $V_{CC}$ ; $V_{os} = V_{CC}$ or $V_{EE}$				
		V <sub>CC</sub> = 5.5 V; V <sub>EE</sub> = 0 V	-	-	160.0	μA
		V <sub>CC</sub> = 5.0 V; V <sub>EE</sub> = -5.0 V	-	-	320.0	μA
Δl <sub>CC</sub>	additional supply current	per input; $V_I = V_{CC}$ - 2.1 V; other inputs at $V_{CC}$ or GND; $V_{CC}$ = 4.5 V to 5.5 V; $V_{EE}$ = 0 V	-	-	220.5	μΑ

#### [1] All typical values are measured at $T_{amb}$ = 25 °C.





## 11. Dynamic characteristics

#### Table 9. Dynamic characteristics for 74HC4052-Q100

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF; for test circuit see Fig. 15.

 $V_{is}$  is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 $V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C					
t <sub>pd</sub>	propagation delay	$V_{is}$ to $V_{os}$ ; $R_L = \infty \Omega$ ; see Fig. 13 [2]				
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	14	75	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	5	15	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	4	13	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	4	10	ns
t <sub>on</sub>	turn-on time	$\overline{E}$ , Sn to $V_{os}$ ; $R_L = \infty \Omega$ ; see Fig. 14 [3]				
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	105	405	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	38	81	ns
		V <sub>CC</sub> = 5.0 V; V <sub>EE</sub> = 0 V; C <sub>L</sub> = 15 pF	-	28	-	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	30	69	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	26	58	ns
t <sub>off</sub>	turn-off time	$\overline{E}$ , Sn to $V_{os}$ ; $R_L = 1 \text{ k}\Omega$ ; see $\overline{Fig. 14}$ [4]				
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	74	315	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	27	63	ns
		V <sub>CC</sub> = 5.0 V; V <sub>EE</sub> = 0 V; C <sub>L</sub> = 15 pF	-	21	-	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	22	54	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	22	48	ns
C <sub>PD</sub>	power dissipation capacitance	per switch; $V_I = GND$ to $V_{CC}$ [5]	-	57	-	pF

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -	40 °C to +125 °C		-1		I	
t <sub>pd</sub>	propagation delay	$V_{is}$ to $V_{os}$ ; $R_L = \infty \Omega$ ; see <u>Fig. 13</u>	]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	90	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	18	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	15	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	12	ns
t <sub>on</sub>	turn-on time	$\overline{E}$ , Sn to $V_{os}$ ; $R_L = \infty \Omega$ ; see $\overline{Fig. 14}$	]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	490	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	98	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	83	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	69	ns
t <sub>off</sub>	turn-off time	$\overline{E}$ , Sn to $V_{os}$ ; $R_L = 1 \text{ k}\Omega$ ; see $\underline{Fig. 14}$	]			
		V <sub>CC</sub> = 2.0 V; V <sub>EE</sub> = 0 V	-	-	375	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V	-	-	75	ns
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	64	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	-	-	57	ns

- [1] All typical values are measured at  $T_{amb}$  = 25 °C.
- $t_{\text{pd}}$  is the same as  $t_{\text{PHL}}$  and  $t_{\text{PLH}}$ . [2]
- $t_{on}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .  $t_{off}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .
- $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

N = number of inputs switching;

 $\Sigma \{ (C_L + C_{sw}) \times V_{CC}^2 \times f_o \} = \text{sum of outputs};$ 

C<sub>L</sub> = output load capacitance in pF;

C<sub>sw</sub> = switch capacitance in pF;

 $V_{CC}$  = supply voltage in V.

#### Table 10. Dynamic characteristics for 74HCT4052-Q100

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF; for test circuit see Fig. 15.

*V*<sub>is</sub> is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 $V_{os}$  is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
T <sub>amb</sub> = -	40 °C to +85 °C						
t <sub>pd</sub>	propagation delay	$V_{is}$ to $V_{os}$ ; $R_L = \infty \Omega$ ; see <u>Fig. 13</u>	[2]				
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V		-	5	15	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V		-	4	10	ns
t <sub>on</sub>	turn-on time	$\overline{E}$ , Sn to $V_{os}$ ; $R_L = 1 \text{ k}\Omega$ ; see $\underline{Fig. 14}$	[3]				
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V		-	41	88	ns
		V <sub>CC</sub> = 5.0 V; V <sub>EE</sub> = 0 V; C <sub>L</sub> = 15 pF		-	18	-	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V		-	28	60	ns
t <sub>off</sub>	turn-off time	$\overline{E}$ , Sn to $V_{os}$ ; $R_L = 1 \text{ k}\Omega$ ; see $\underline{Fig. 14}$	[4]				
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V		-	26	63	ns
		V <sub>CC</sub> = 5.0 V; V <sub>EE</sub> = 0 V; C <sub>L</sub> = 15 pF		-	13	-	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V		-	21	48	ns
C <sub>PD</sub>	power dissipation capacitance	per switch; V <sub>I</sub> = GND to V <sub>CC</sub> - 1.5 V	[5]	-	57	-	pF
T <sub>amb</sub> = -	40 °C to +125 °C						
t <sub>pd</sub>	propagation delay	$V_{is}$ to $V_{os}$ ; $R_L = \infty \Omega$ ; see <u>Fig. 13</u>	[2]				
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V		-	-	18	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V		-	-	12	ns
t <sub>on</sub>	turn-on time	$\overline{E}$ , Sn to V <sub>os</sub> ; R <sub>L</sub> = 1 k $\Omega$ ; see $\underline{Fig. 14}$	[3]				
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V		-	-	105	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V		-	-	72	ns
t <sub>off</sub>	turn-off time	$\overline{E}$ , Sn to $V_{os}$ ; $R_L = 1 \text{ k}\Omega$ ; see $\underline{Fig. 14}$	[4]				
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V		-	-	75	ns
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V		-	-	57	ns

- [1] All typical values are measured at  $T_{amb}$  = 25 °C.
- $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .
- [3]
- $t_{on}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .  $t_{off}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .
- [5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

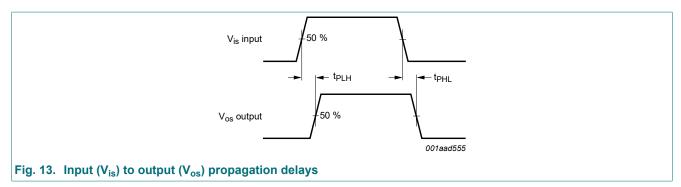
N = number of inputs switching;

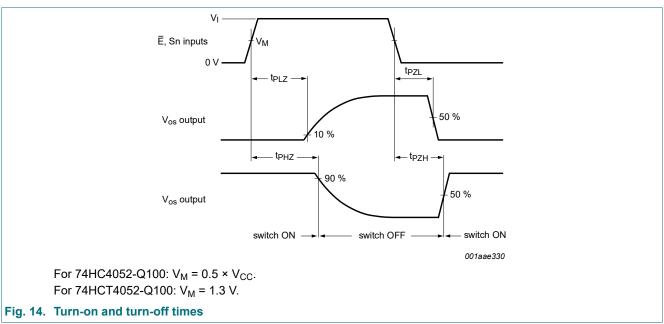
 $\Sigma$ {(C<sub>L</sub> + C<sub>sw</sub>) x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>} = sum of outputs;

C<sub>L</sub> = output load capacitance in pF;

C<sub>sw</sub> = switch capacitance in pF;

V<sub>CC</sub> = supply voltage in V.





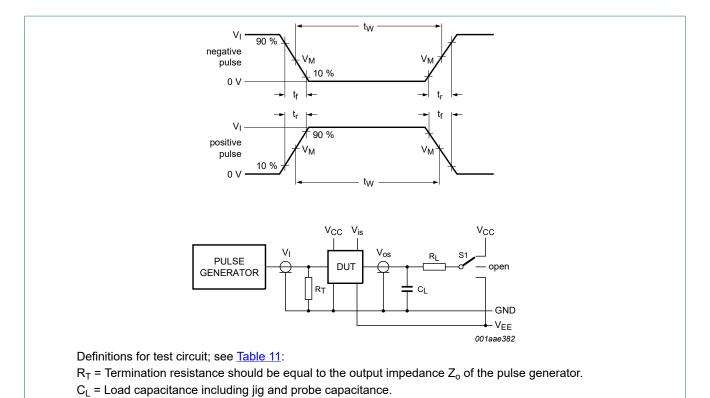


Fig. 15. Test circuit for measuring switching times

R<sub>L</sub> = Load resistance. S1 = Test selection switch.

Table 11. Test data

Test	Input			Load	Load		
	V <sub>I</sub> [1]	V <sub>is</sub>	t <sub>r</sub> , t <sub>f</sub>	t <sub>r</sub> , t <sub>f</sub>		R <sub>L</sub>	
			at f <sub>max</sub>	other [2]			
t <sub>PHL</sub> , t <sub>PLH</sub>	V <sub>CC</sub>	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open
t <sub>PZH</sub> , t <sub>PHZ</sub>	V <sub>CC</sub>	V <sub>CC</sub>	< 2 ns	6 ns	50 pF	1 kΩ	V <sub>EE</sub>
t <sub>PZL</sub> , t <sub>PLZ</sub>	V <sub>CC</sub>	V <sub>EE</sub>	< 2 ns	6 ns	50 pF	1 kΩ	V <sub>CC</sub>

<sup>[1]</sup> For 74HCT4052-Q100: V<sub>I</sub> = 3 V

<sup>[2]</sup>  $t_r = t_f = 6$  ns; when measuring  $f_{max}$ , there is no constraint to  $t_r$  and  $t_f$  with 50 % duty factor.

### 11.1. Additional dynamic characteristics

#### Table 12. Additional dynamic characteristics

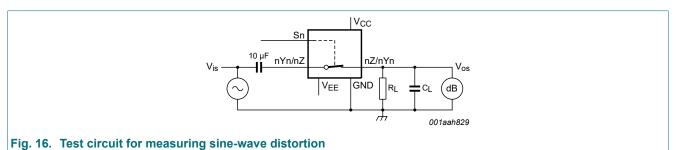
Recommended conditions and typical values; GND = 0 V;  $T_{amb}$  = 25 °C;  $C_L$  = 50 pF.

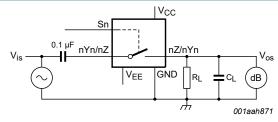
 $V_{is}$  is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 $V_{os}$  is the output voltage at pins nYn or nZ, whichever is assigned as an output.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
d <sub>sin</sub>	sine-wave	$f_i$ = 1 kHz; $R_L$ = 10 kΩ; see <u>Fig. 16</u>					
	distortion	$V_{is} = 4.0 \text{ V (p-p)}; V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$		-	0.04	-	%
		$V_{is} = 8.0 \text{ V (p-p)}; V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$		-	0.02	-	%
		$f_i$ = 10 kHz; $R_L$ = 10 k $\Omega$ ; see <u>Fig. 16</u>					
		$V_{is} = 4.0 \text{ V (p-p)}; V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$		-	0.12	-	%
		$V_{is} = 8.0 \text{ V (p-p)}; V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$		-	0.06	-	%
$\alpha_{iso}$	isolation	$R_L = 600 \Omega$ ; $f_i = 1 MHz$ ; see Fig. 17					
	(OFF-state)	V <sub>CC</sub> = 2.25 V; V <sub>EE</sub> = -2.25 V	[1]	-	-50	-	dB
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	[1]	-	-50	-	dB
Xtalk	crosstalk	between two switches/multiplexers; $R_L$ = 600 $\Omega$ ; $f_i$ = 1 MHz; see Fig. 18					
		V <sub>CC</sub> = 2.25 V; V <sub>EE</sub> = -2.25 V	[1]	-	-60	-	dB
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	[1]	-	-60	-	dB
V <sub>ct</sub>	crosstalk voltage	peak-to-peak value; between control and any switch; $R_L$ = 600 $\Omega$ ; $f_i$ = 1 MHz; $E$ or Sn square wave between $V_{CC}$ and GND; $t_r$ = $t_f$ = 6 ns; see Fig. 19					
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = 0 V		-	110	-	mV
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V		-	220	-	mV
f <sub>(-3dB)</sub>	-3 dB frequency	$R_L$ = 50 Ω; see <u>Fig. 20</u>					
	response	V <sub>CC</sub> = 2.25 V; V <sub>EE</sub> = -2.25 V	[2]	-	170	-	MHz
		V <sub>CC</sub> = 4.5 V; V <sub>EE</sub> = -4.5 V	[2]	-	180	-	MHz

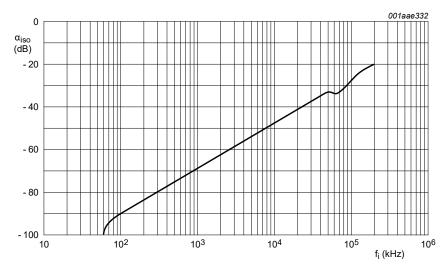
- Adjust input voltage  $V_{is}$  to 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ). Adjust input voltage  $V_{is}$  to 0 dBm level at  $V_{os}$  for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ).





 $V_{CC}$  = 4.5 V; GND = 0 V;  $V_{EE}$  = -4.5 V;  $R_L$  = 600  $\Omega;$   $R_S$  = 1 k $\Omega.$ 

a. Test circuit



b. Isolation (OFF-state) as a function of frequency

Fig. 17. Test circuit for measuring isolation (OFF-state)

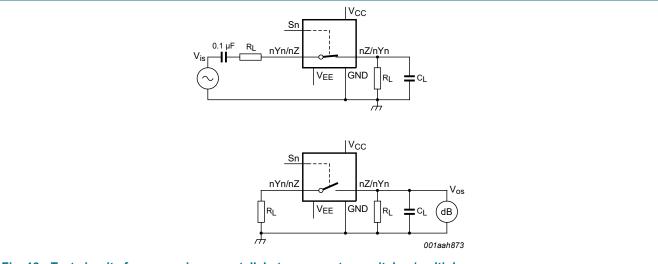


Fig. 18. Test circuits for measuring crosstalk between any two switches/multiplexers

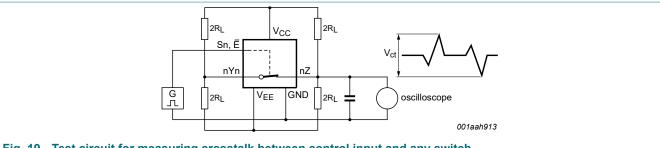
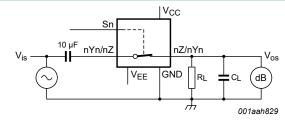
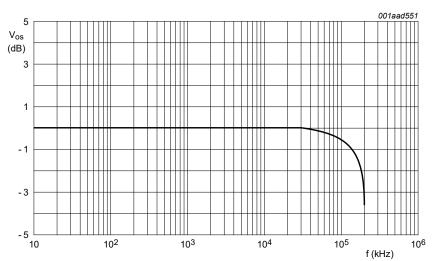


Fig. 19. Test circuit for measuring crosstalk between control input and any switch



 $V_{CC}$  = 4.5 V; GND = 0 V;  $V_{EE}$  = -4.5 V;  $R_L$  = 50  $\Omega$ ;  $R_S$  = 1 k $\Omega$ .

a. Test circuit



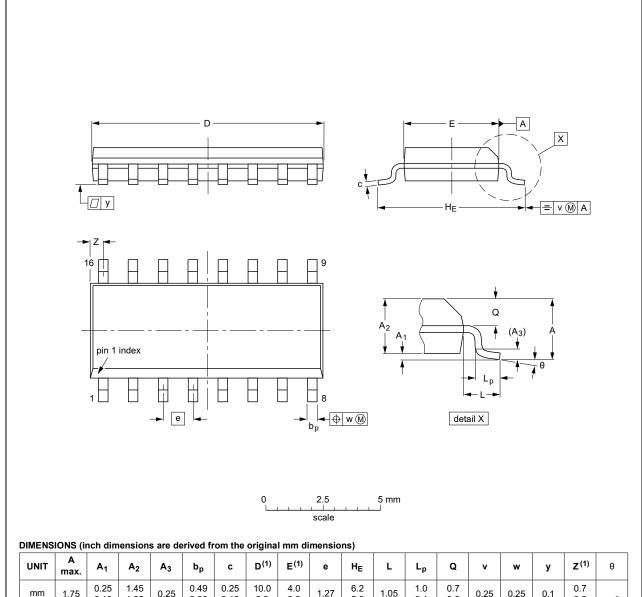
b. Typical frequency response

Fig. 20. Test circuit for frequency response

### 12. Package outline

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	<b>A</b> <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

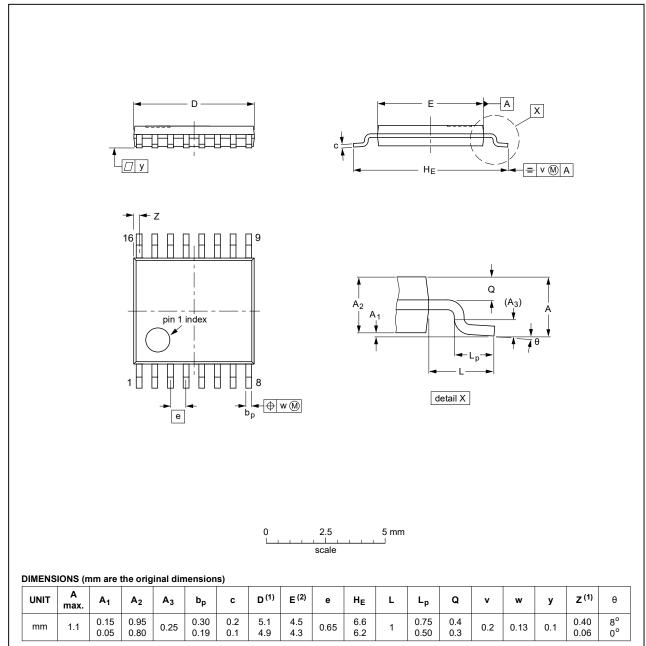
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19	

Fig. 21. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18

Fig. 22. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

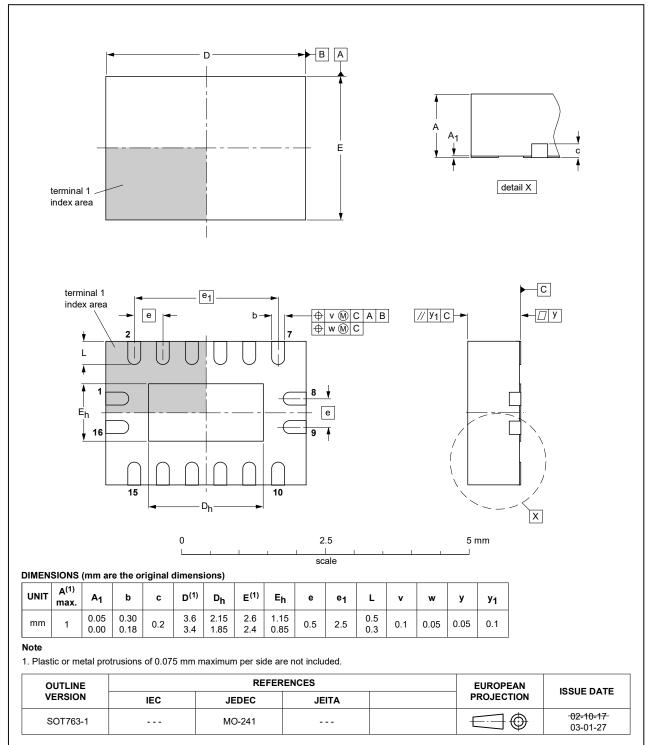


Fig. 23. Package outline SOT763-1 (DHVQFN16)

### 13. Abbreviations

#### **Table 13. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model

### 14. Revision history

#### **Table 14. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4052_Q100 v.3	20200227	Product data sheet	-	74HC_HCT4052_Q100 v.2
Modifications:	guidelines o Legal texts	have been adapted to the rating values for P <sub>tot</sub> total p	new company nan	ne where appropriate.
74HC_HCT4052_Q100 v.2	20121122	Product data sheet	-	74HC_HCT4052_Q100 v.1
Modifications:	CDM added			
74HC_HCT4052_Q100 v.1	20120720	Product data sheet	-	-

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

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### **Contents**

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Ordering information	2
5. Functional diagram	2
6. Pinning information	4
6.1. Pinning	4
6.2. Pin description	4
7. Functional description	5
8. Limiting values	5
9. Recommended operating conditions	6
10. Static characteristics	7
11. Dynamic characteristics	12
11.1. Additional dynamic characteristics	17
12. Package outline	
13. Abbreviations	
14. Revision history	23
15. Legal information	24

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